







# **Data sheet**

MODEL: TG5032CDN 30.720000MHz CHGNDA

Product. No. : X1G0050610103xx

Please refer to the 10.Packing information about xx (last 2 digits)

# **SEIKO EPSON CORPORATION**



Pb free.



Complies with EU RoHS directive.

\*About the products without the Pb-free mark.

Contains Pb in products exempted by EU RoHS directive.

(Contains Pb in sealing glass, high melting temperature type solder or other.)

#### INTRODUCTION

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# [1] Characteristics

· Package size (5.0 mm×3.2 mm×1.45 mm)

· Ultra high stability VC-TCXO

· Output waveform : CMOS

· Reference weight Typ.72mg

[2] Absolute maximum ratings

12 ] Absolute maximum ratings									
Parameter	Symbol	Specifications			Unit	Conditions			
raiailletei	Symbol	Min.	Тур.	Max.	Offic	Conditions			
Supply voltage	Vcc-GND	-0.6	-	+6.0	V	-			
Frequency control voltage	Vc-GND	-0.6	-	Vcc+0.6	V	Vc terminal			
Storage temperature range	T_stg	-40	-	+90	°C	Storage as single product.			

[3] Recommended operating conditions

Parameter	Symbol	Specifications			Unit	Conditions	
	Syllibol	Min.	Тур.	Max.	Offic	Conditions	
Supply voltage	Vcc	3.135	3.3	3.465	V	-	
Supply voltage	GND	0	-	0	V	-	
Frequency control voltage	Vc	0.5	1.5	2.5	V	Vc=1.5 +/-1.0V	
Operating temperature range	T_use	-40	-	+85	°C	-	
Output load	Load_C	13.5	15	16.5	pF	-	

# [4] Frequency characteristics

(1) Frequency characteristics

(Vcc=3.3 V, GND=0.0 V, Vc=1.5 V, Load=15 pF, T\_use=+25°C)

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Parameter	Symbol	Symbol Specifications			Unit	Conditions	
Faianietei	Symbol	Min.	Тур.	Max.	Offic	Conditions	
Output Frequency	fo	-	30.72	-	MHz	-	
Frequency tolerance *1	f_tol	-2.0	-	+2.0	x10 <sup>-6</sup>	T_use=+25°C+/-2°C After 2 reflows *2	
Frequency / temperature characteristics	fo-Tc	-0.25	-	+0.25	x10 <sup>-6</sup>	T_use=-40°C to +85°C (Reference to +25°C)	
Frequency / load coefficient	fo-Load	-0.1	-	+0.1	x10 <sup>-6</sup>	Load +/- 10%	
Frequency / voltage coefficient	fo-Vcc	-0.1	-	+0.1	x10 <sup>-6</sup>	Vcc +/-5%	
Frequency aging	f ogo	-0.02	-	+0.02	x10 <sup>-6</sup>	T_use = +25°C, 24 hours *3	
l requericy aging	f_age	-1.0	-	+1.0	x10 <sup>-6</sup>	T_use = +25°C 1 year	

<sup>\*1</sup> Include initial frequency tolerance and frequency deviation after reflow cycles.

<sup>\*2</sup> Measured in the elapse of 24 hours after reflow soldering.

<sup>\*3</sup> After 48 hours of continuous operation



(2) Frequency control characteristics

(Vcc=3.3 V, GND=0.0 V, Vc=1.5 V, Load=15 pF, T\_use=+25°C)

Parameter	Symbol	Specifications			Unit	Conditions	
Faianietei	Symbol	Min.	Тур.	Max.	Offic	Conditions	
Frequency control range	f_cont	-10.0	-	-5.0	x10 <sup>-6</sup>	Vc=0.5V	
		+5.0	-	+10.0	x10 <sup>-6</sup>	Vc=2.5V	
Input impedance	Zin	100		kΩ	Vc=1.5V		
Frequency change polarity	-	Positive polarity			-	-	

[5] Electrical characteristics

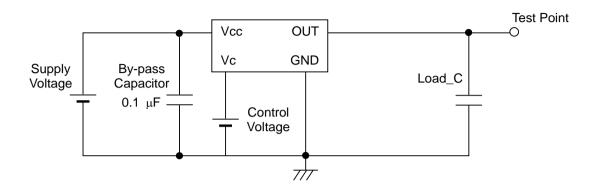
(Vcc=3.3 V, GND=0.0 V, Vc=1.5 V, Load=15 pF, T\_use=+25°C)

[ O ] Licotribal orial actoris		(100-0.0 1, 0.112-0.0 1, 10-1.0 1, 1200-120 t					
Parameter	Symbol	Specifications			Unit	Conditions	
raiailletei	Symbol	Min.	Тур.	Max.	Offic	Conditions	
Current consumption	lcc	-	-	6.0	mA	Vcc=3.3V	
High level output voltage	Voн	90%Vcc	90%Vcc V		V	-	
Low level output voltage	Vol	1	-	10%Vcc	V	-	
Rise time	tr	-	-	8.0	ns	10% Vcc to 90% Vcc level	
Fall time	tf	-	-	8.0	ns	90% Vcc to 10% Vcc level	
Symmetry	SYM	45	-	55	%	50 % Vcc Level	
		-	-64	-		1Hz offset	
		-	-90	-		10Hz offset	
		-	-114	-		100Hz offset	
Phase noise	L(f)	-	-136	-	dBc/Hz	1kHz offset	
		-	-151	-		10kHz offset	
		-	-155	-		100kHz offset	
		-	-156	-		1MHz offset	

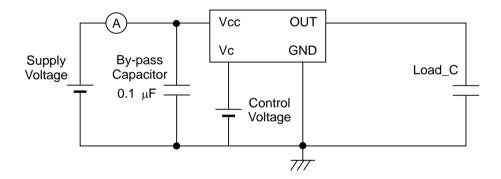


## [6] Test circuit

## 1) Output Load: Load\_C = 15 pF



#### 2) Current consumption



#### 3) Conditions

1. Oscilloscope: Impedance Min.  $1M\Omega$ 

Input capacitance Max. 10 pF Band width Min. 300 MHz

Impossible to measure both frequency and wave form at the same time.

(In case of using oscilloscope's amplifier output, possible to measure both at the same time.)

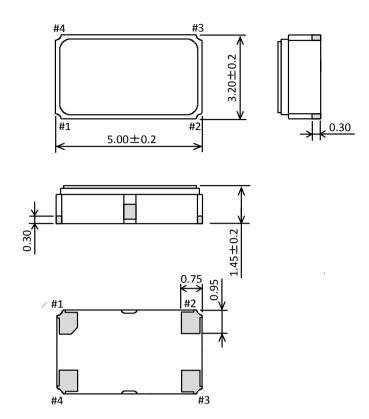
- 2. Load\_C includes probe capacitance.
- 3. A capacitor (By-pass:0.1 µF) is placed between Vcc and GND, and closely to TCXO.
- 4. Use the current meter whose internal impedance value is small.
- 5. Power Supply

Impedance of power supply should be as low as possible.

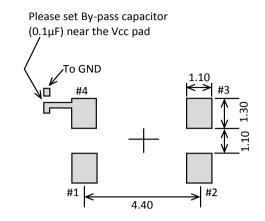
6. GND pin should be connected to low impedance GND.



## [7] Outline drawing unit:mm



## [8] Recommended foot print unit:mm

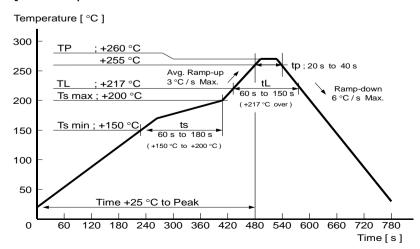


Pin#	Connection
1	Vc
2	GND
3	OUT
4	Vcc

To maintain stable operation, provide a  $0.1~\mu F$  by-pass capacitor at a location as near as possible to the power source terminal of the crystal product (between Vcc - GND).

# Material Ceramics(Cavity) Au plated nickel(Electric terminal) Fe-Ni-Co(Lid)

## [9] Reflow profile





# [ 10 ] Packing information

1) Product number last 2 digits code(xx) description. The recommended code is "00" X1G0050610103xx

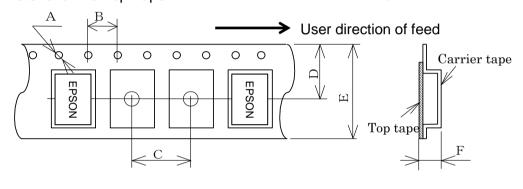
Code	Condition
00	1000pcs / Reel
01	Any Q'ty vinyl bag(Tape cut)
11	Any Q'ty / Reel
12	250pcs / Reel
13	500pcs / Reel

## 2) Taping specification

Subject to EIA-481 & IEC-60286

(1) Tape dimensions TE0804L Material of the Carrier Tape : PS Material of the Top Tape : PET+PE

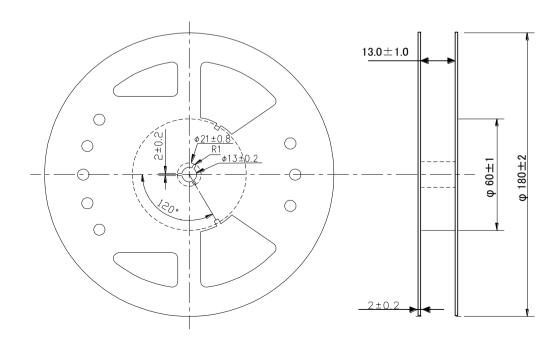
unit:mm



3	Symbol	Α	В	С	D	Е	F
	Value	Ф1.5	4.0	8.0	7.25	12.0	1.4

## (2) Reel dimensions

Center material : PS Material of the Reel : PS





#### [11] Handling precautions

Prior to using this product, please carefully read the section entitled "Precautions" on our Web site ( http://www5.epsondevice.com/en/quartz/tech/precaution/ ) for instructions on how to handle and use the product properly to ensure optimal performance of the product in your equipment. Before using the product under any conditions other than those specified therein, please consult with us to verify and confirm that the performance of the product will not be negatively affected by use under such conditions.

In addition to the foregoing precautions, in order to avoid the deteriorating performance of the product, we strongly recommend that you DO NOT use the product under ANY of the following conditions:

- (1) Mounting the product on a board using water-soluble solder flux and using the product without removing the residue of the flux completely from the board. The residue of such flux that is soluble in water or water-soluble cleaning agent, especially the residues which contains active halogens, will negatively affect the performance and reliability of the product.
- (2) Using the product in any manner that will result in any shock or impact to the product.
- (3) Using the product in places where the product is exposed to water, chemicals, organic solvent, sunlight, dust, corrosive gasses, or other materials.
- (4) Using the product in places where the product is exposed to static electricity or electromagnetic waves.
- (5) Applying ultrasonic cleaning without advance verification and confirmation that the product will not be affected by such a cleaning process, because it may damage the crystal, IC and/or metal line of the product.
- (6) Touching the IC surface with tweezers or other hard materials directly.
- (7) Using the product under any other conditions that may negatively affect the performance and/or reliability of the product.
- (8) Power supply with ripple may cause of incorrect operation or degradation of phase noise characteristics, so please evaluate before use.
- (9) Frequency aging is from environmental tests results to the expectation of the amount of the frequency variation. This doesn't guarantee the product-life cycle.

Should any customer use the product in any manner contrary to the precautions and/or advice herein, such use shall be done at the customer's own risk.



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